



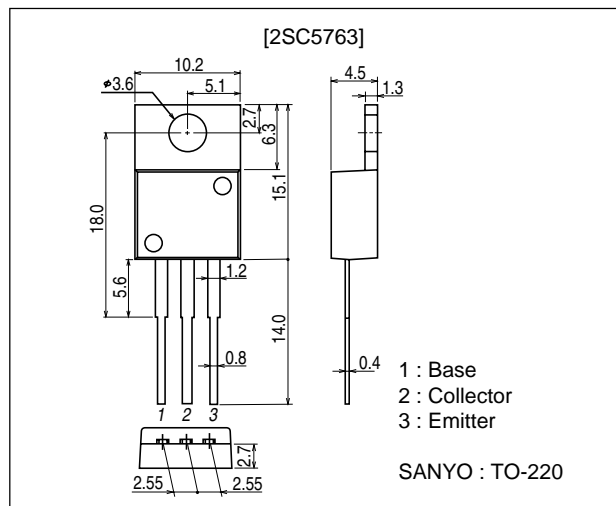
Switching Regulator Applications

Features

- High breakdown voltage.
- High reliability.
- High-speed switching.
- Wide ASO.
- Adoption of MBIT process.

Package Dimensions

unit : mm
2010C



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		700	V
Collector-to-Emitter Voltage	V _{CEO}		400	V
Emitter-to-Base Voltage	V _{EBO}		8	V
Collector Current	I _C		7	A
Collector Current (Pulse)	I _{CP}	PW≤300μs, Duty cycle≤10%	14	A
Collector Dissipation	P _C		1.75	W
		T _c =25°C	55	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} =400V, I _E =0			10	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V, I _C =0			10	μA

Continued on next page.

* : The h_{FE}1 of the 2SC5763 is classified as follows.

Rank	M	N
h _{FE} 1	20 to 40	30 to 50

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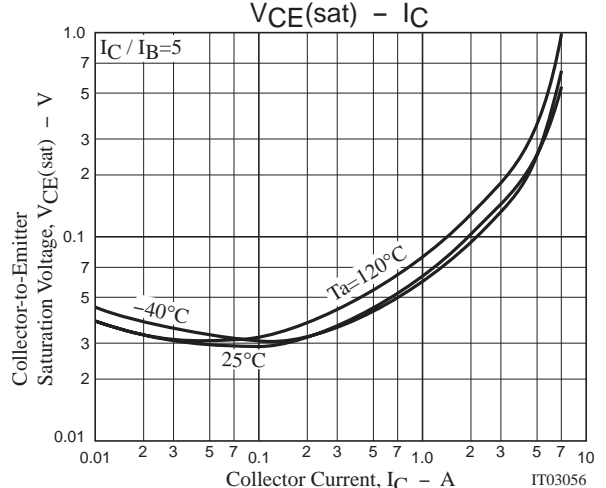
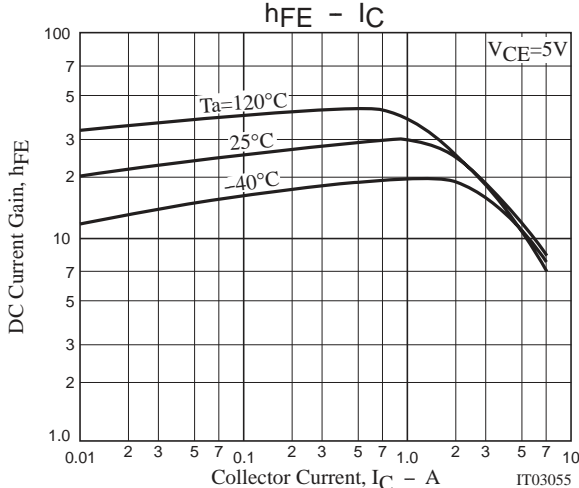
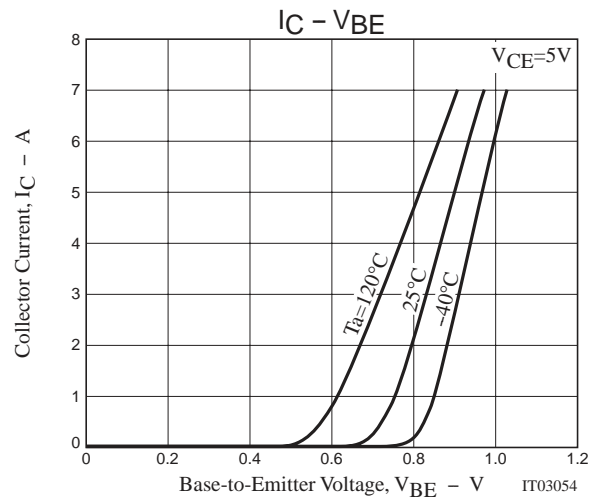
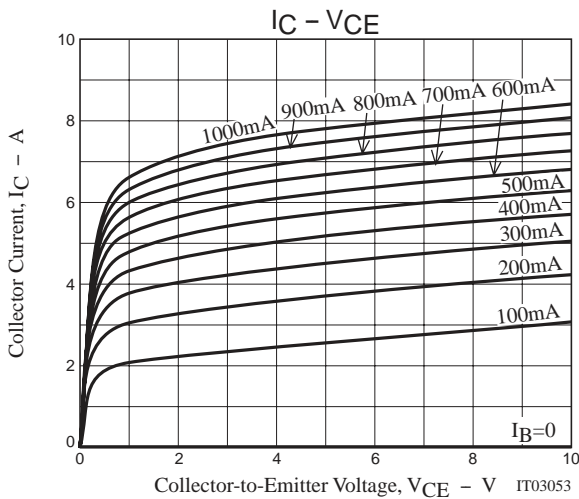
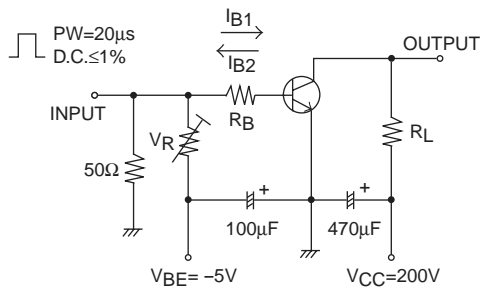
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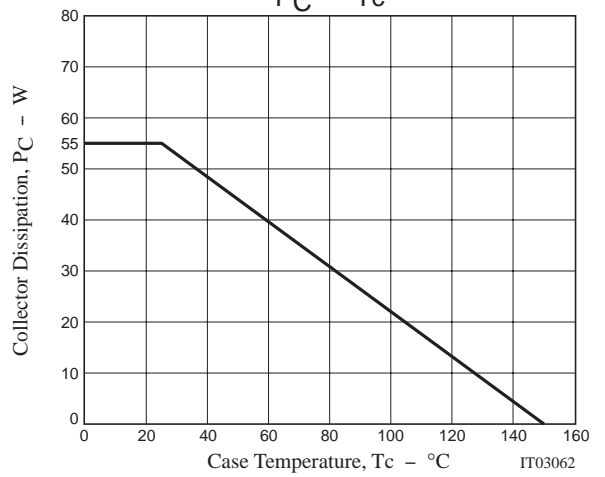
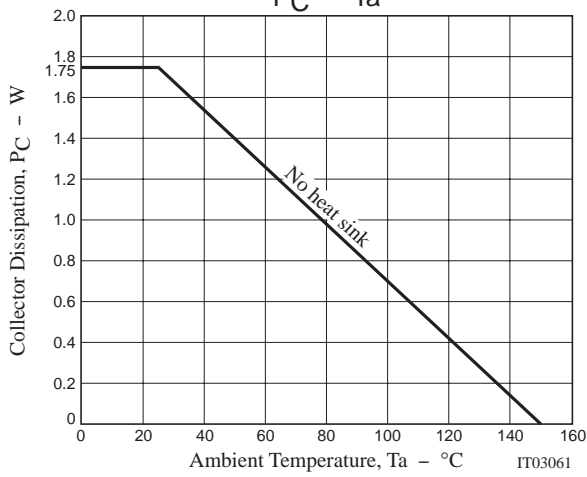
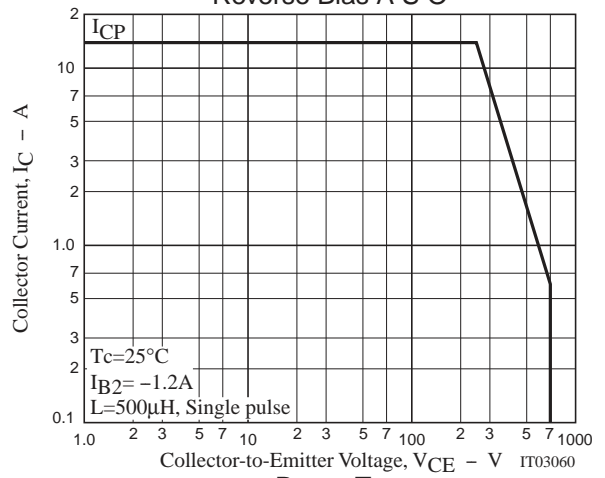
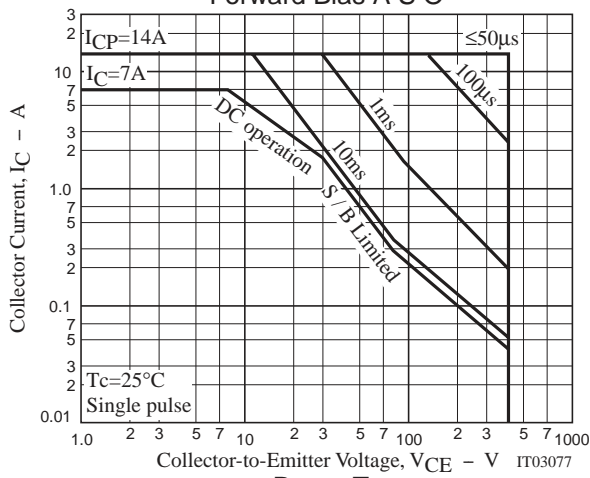
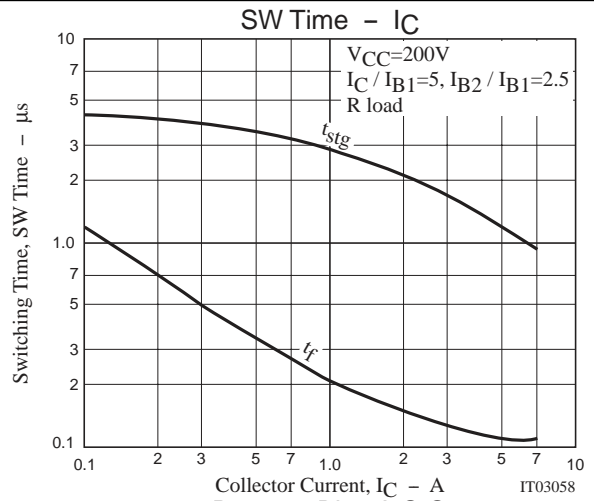
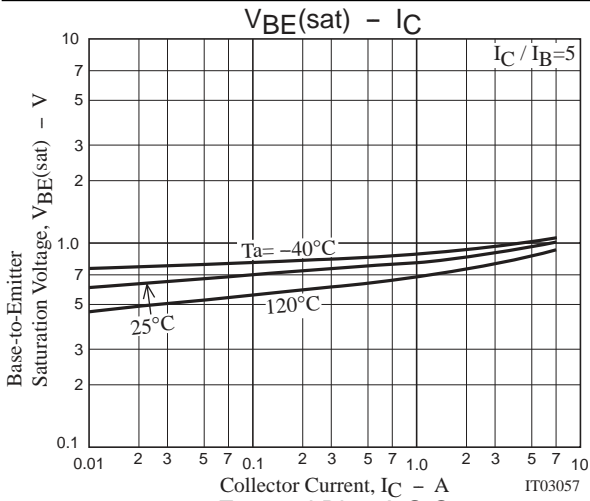
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
DC Current Gain	hFE1	VCE=5V, IC=0.8A	20*		50*	
	hFE2	VCE=5V, IC=4A	10			
	hFE3	VCE=5V, IC=1mA	10			
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=4A, IB=0.8A			0.8	V
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=4A, IB=0.8A			1.5	V
Gain-Bandwidth Product	fT	VCE=10V, IC=0.8A		17		MHz
Output Capacitance	Cob	VCB=10V, f=1MHz		80		pF
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=1mA, IE=0	700			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=5mA, RBE=∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=1mA, IC=0	8			V
Turn-On Time	ton	IC=5A, IB1=1A, IB2=-2A, RL=40Ω, VCC=200V			0.5	μs
Storage Time	tstg	IC=5A, IB1=1A, IB2=-2A, RL=40Ω, VCC=200V			2.5	μs
Fall Time	tf	IC=5A, IB1=1A, IB2=-2A, RL=40Ω, VCC=200V			0.25	μs

Switching Time Test Circuit





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